

TOSHIBA Bi-CMOS Integrated Circuit Silicon Monolithic

TB6569FG/FTG

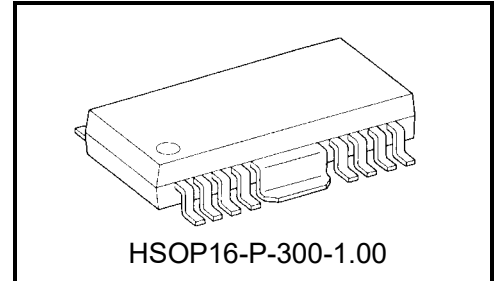
Full-Bridge DC Motor Driver IC

1. Description

The TB6569FG/FTG is a full-bridge DC motor driver with MOS output transistors.

The low ON-resistance MOS process and PWM control enables driving DC motors with high thermal efficiency.

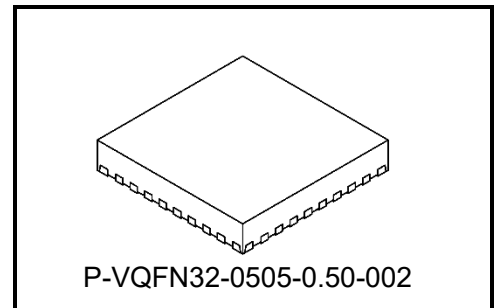
Four operating modes are selectable via IN1 and IN2: clockwise (CW), counterclockwise (CCW), Short Brake and Stop.



TB6569FG: Weight: 0.5 g (typ.)

2. Features

- Power supply voltage: 50 V (max)
- Output current: 4.5 A (max)
- Direct PWM control
- PWM constant-current control
- CW/CCW/Short Brake/Stop modes
- Overcurrent shutdown circuit (ISD)
- Overcurrent detection threshold control
- Overcurrent detection time control
- Overvoltage shutdown circuit (VSD)
- Thermal shutdown circuit (TSD)
- Undervoltage lockout circuit (UVLO)
- Dead time for preventing shoot-through current



TB6569FTG: Weight: 0.07 g (typ.)

3. Block Diagram (application circuit example)

The application circuits shown in this document are provided for reference purposes only. Thorough evaluation is required, especially at the mass production design stage. Toshiba does not grant any license to any industrial property rights by providing these examples of application circuits.

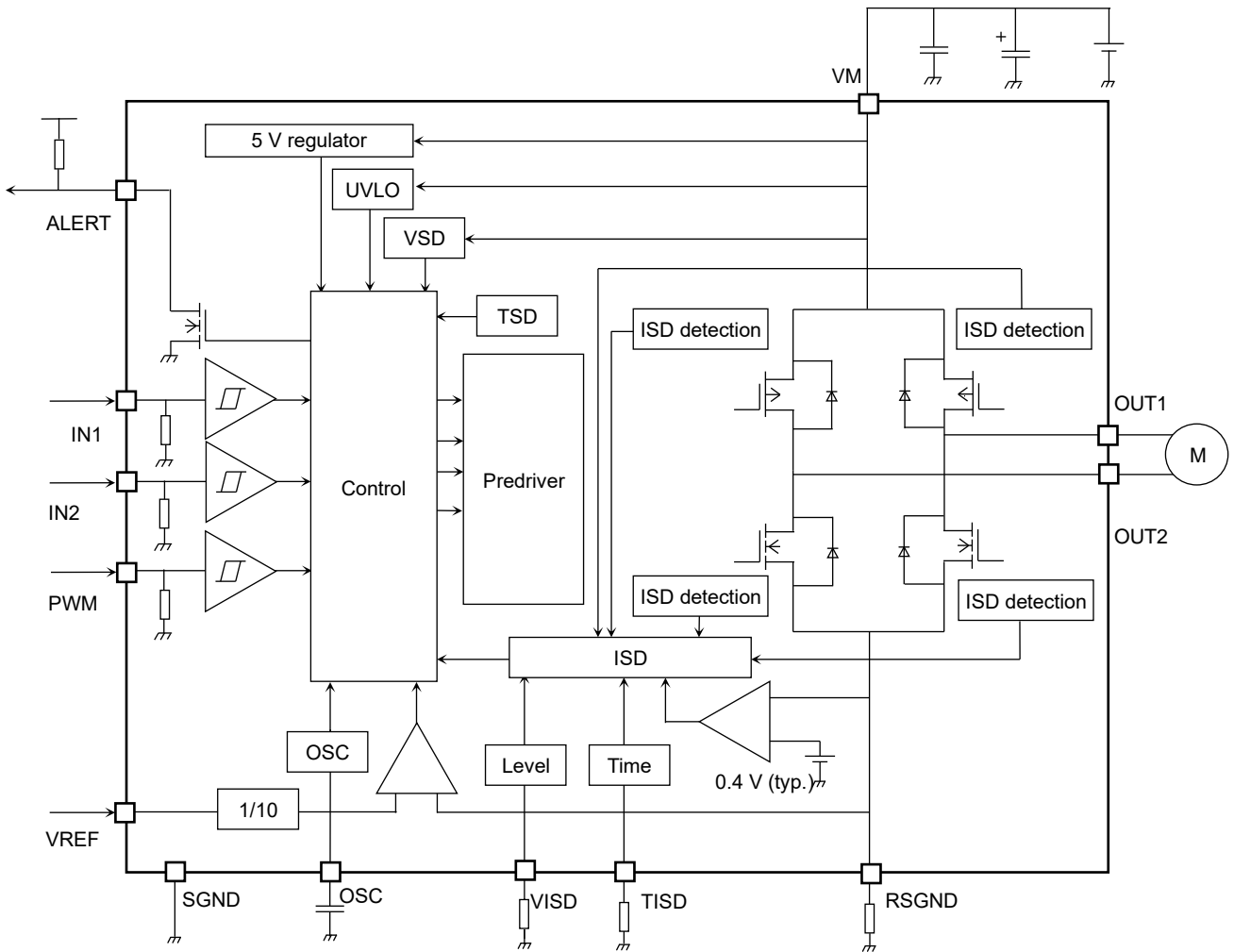


Figure 3 Block Diagram

4. Pin Functions: TB6569FG

Table 4 TB6569FG Pin Functions

Pin No.	Pin Name	Functional Description
1	ALERT	Error detection output pin
2	OSC	Capacitor pin for controlling oscillation frequency for the PWM constant-current control
3	IN1	Control signal input pin 1
4	SGND	Small signal ground pin
5	IN2	Control signal input pin 2
6	N.C.	No-connect
7	OUT1	Output pin 1
8	RSGND	Power ground pin/ Detection resistor pin for PWM constant-current control
9	N.C.	No-connect
10	OUT2	Output pin 2
11	N.C.	No-connect (Note 1)
12	VM	Power supply voltage pin
13	VISD	Resistor pin for overcurrent detection threshold control
14	TISD	Resistor pin for overcurrent detection time control
15	PWM	PWM input pin
16	VREF	Supply voltage pin for PWM constant-current control
—	FIN	Pin-fin heat sink (Note 2)

Note 1: ESD test is not conducted on N.C. pins.

Note 2: Since the pin-fin is provided for discharging heat, the thermal design must be considered on the PCB designing. (The fin is installed on the second surface of the chip and electrified; therefore, it must be insulated or earthed to the ground.)

5. Pin Assignment (top view): TB6569FG

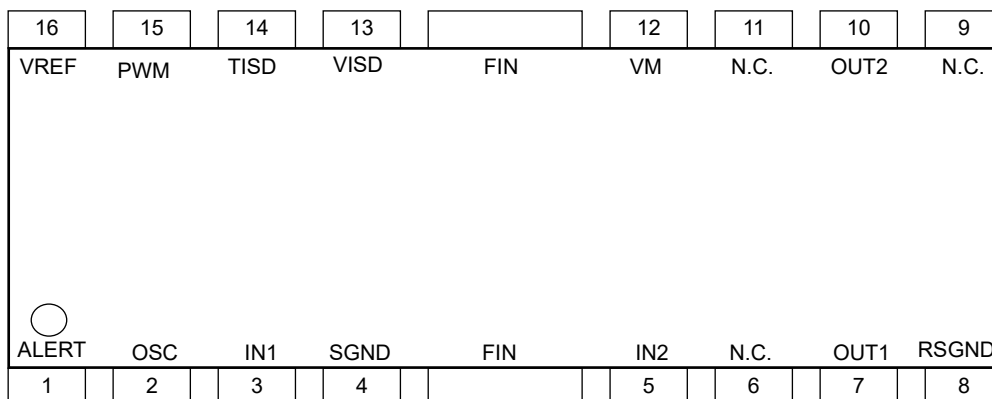


Figure 5 TB6569FG Pin Assignment

6. Pin Functions: TB6569FTG (Note)

Table 6 TB6569FTG Pin Functions

Pin No.	Pin Name	Functional Description
1	OUT1	Output pin 1 (Note 1)
2	OUT1	Output pin 1
3	N.C.	No-connect
4	RSGND	Power ground pin/ Detection resistor pin for PWM constant-current control
5	RSGND	Power ground pin/ Detection resistor pin for PWM constant-current control
6	N.C.	No-connect
7	OUT2	Output pin 2
8	OUT2	Output pin 2
9	N.C.	No-connect
10	N.C.	No-connect
11	VM	Power supply voltage pin
12	VM	Power supply voltage pin
13	N.C.	No-connect
14	N.C.	No-connect
15	VISD	Resistor pin for overcurrent detection threshold control
16	N.C.	No-connect
17	TISD	Resistor pin for overcurrent detection time control
18	PWM	PWM input pin
19	VREF	Supply voltage pin for PWM constant-current control
20	N.C.	No-connect
21	N.C.	No-connect
22	ALERT	Error detection output pin
23	OSC	Capacitor pin for controlling oscillation frequency for the PWM constant-current control
24	IN1	Control signal input pin 1
25	N.C.	No-connect
26	SGND	Small signal ground pin
27	SGND	Small signal ground pin
28	N.C.	No-connect
29	N.C.	No-connect
30	N.C.	No-connect
31	IN2	Control signal input pin 2
32	N.C.	No-connect (Note 2)

Note: Design the pattern in consideration of the heat design because the back side has the role of heat radiation. (The back side should be connected to GND because it is connected to the back of the chip electrically.)

Note 1: Though each OUT1, RSGND, OUT2, VM, and SGND has two pins, short out these two pins at the external IC respectively.

Note 2: ESD test is not conducted on N.C. pins.

7. Pin Assignment (top view): TB6569FTG

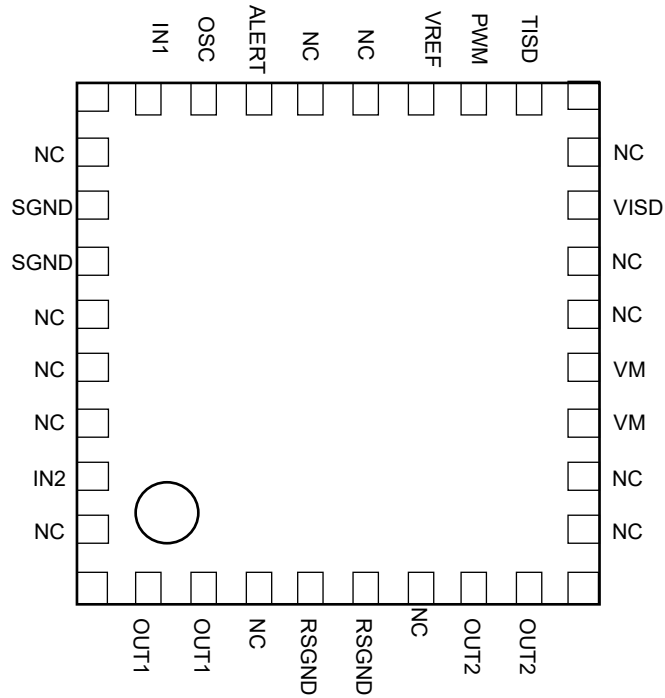


Figure 7 TB6569FTG Pin Assignment

8. Absolute Maximum Ratings (Note) (T_a = 25°C)

Table 8 Absolute Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _M	50	V
Output voltage	V _O	50 (Note 1)	V
Output current 1	I _{O peak1}	4.5 (Note 2)	A
Output current 2	I _{O peak2}	4.0 (Note 3)	A
Input voltage	V _{IN}	-0.3 to 5.5	V
ALERT pin output voltage	V _{ALERT}	5.5	V
ALERT pin output current	I _{ALERT}	5	mA
Power dissipation(TB6569FG)	P _{D1}	0.89 (Note4)	W
Power dissipation(TB6569FTG)	P _{D2}	3 (Note 5)	W
Operating temperature	T _{opr}	-40 to 85	°C
Storage temperature	T _{stg}	-55 to 150	°C

Note: The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings. Exceeding the rating (s) may cause the device breakdown, damage, or deterioration, and may result injury by explosion or combustion. Please use the TB6569FG/FTG within the specified operating ranges.

Note 1: OUT1, OUT2

Note 2: The absolute maximum output current rating of 4.5 A must be kept for OUT1 and OUT2 when V_M ≤ 36 V.

Note 3: The absolute maximum output current rating of 4.0 A must be kept for OUT1 and OUT2 when V_M >36 V.

Note 4: IC only

Note 5: On the PCB (Four-layer board is based on JEDEC standard.)

9. Operating Ranges

Table 9 Operating Ranges

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{Mopr}	10 to 45	V
OSC frequency	f _{OSC}	Up to 500	kHz
VREF pin input voltage	V _{REFopr}	0 to 3.6	V
PWM frequency	f _{PWM}	Up to 100	kHz
Output current	I _{O (Ave.)}	Up to 1.5 (Note 6) (given as a guide)	A

Note 6: The average output current shall be increased or decreased depending on usage conditions such as ambient temperature and IC mounting method). Use the average output current so that the junction temperature of 150°C (T_j) and the absolute maximum output current rating of 4.5 A or 4.0 A are not exceeded.

10. Electrical Characteristics (unless otherwise specified, Ta = 25°C, VM = 24 V)

Table 10 Electrical Characteristics

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Power supply voltage		I _{CC1}	Stop mode	-	3	8	mA
		I _{CC2}	CW/CCW mode	-	3	8	
		I _{CC3}	Short Brake mode	-	3	8	
Control circuit IN1 pin, IN2 pin, PWM pin	Input voltage	V _{INH}		2	-	5.5	V
		V _{INL}		0	-	0.8	
	Hysteresis voltage	V _{IN (HYS)}		-	0.4	-	μA
	Input current	I _{INH}	V _{IN} = 5 V	-	50	75	
I _{INL}		V _{IN} = 0 V	-	-	5		
VREF pin input current		I _{INVREF}		-3	-	3	μA
Constant-current control amplifier offset		V _{OFFSET}	RSGND = VREF	-	1	-	mV
PWM frequency		f _{PWM}	Duty: 50 %	-	100	-	kHz
PWM minimum pulse width		f _{PWM (TW)}	(Given as a guide only)	1	-	-	μs
OUT1 pin, OUT2 pin	Output ON resistance	R _{ON (U + L)}	I _O = 3 A	-	0.55	0.9	Ω
	Output leakage current	I _{L (U)}	V _M = 50 V, V _{OUT} = 0 V	-2	-	-	μA
		I _{L (L)}	V _M = V _{OUT} = 50 V	-	-	2	
	Diode forward voltage	V _{F (U)}	I _O = 3 A	-	1.3	1.7	V
V _{F (L)}		I _O = -3 A	-	1.3	1.7		
ALERT pin	Output fall time voltage	V _{AL (LO)}	I _{ALERT} = 1 mA	-	-	0.4	V
	Output leakage current	I _{AL (LE)}	V _{ALERT} = 5.5 V	-	-	2	μA
OSC charge/discharge current		I _{OSC}		0.3	0.5	0.7	mA

11. Thermal Performance Characteristics

• TB6569FG

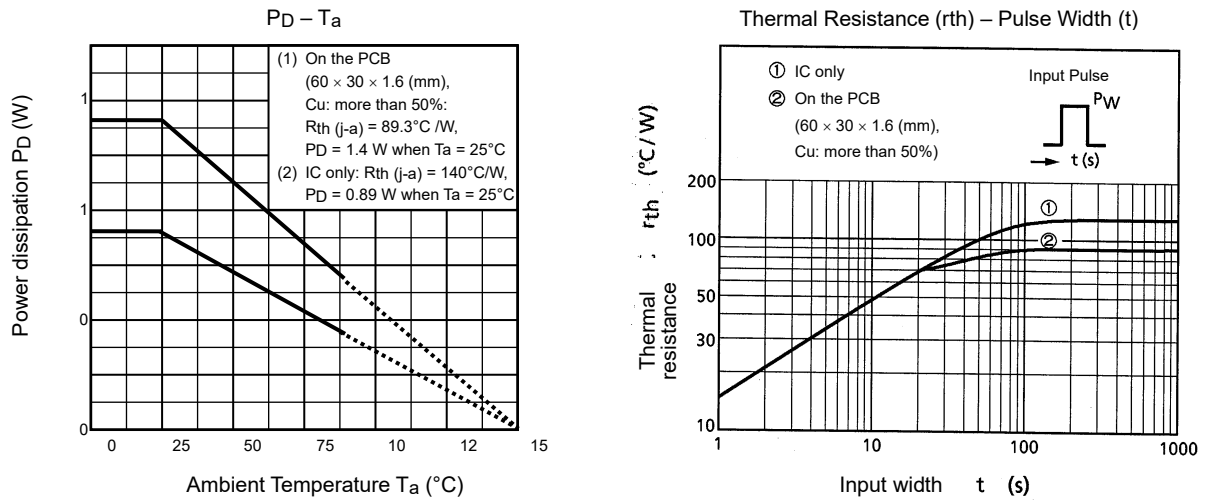


Figure 11.1 TB6569FG Thermal Performance Characteristics

• TB6569FTG

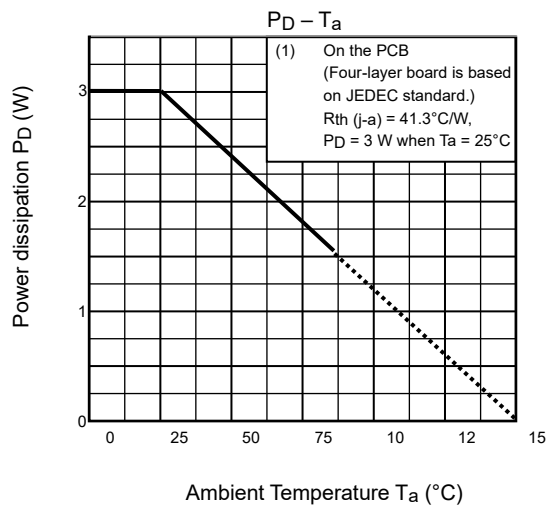
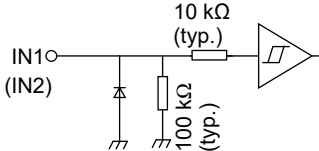
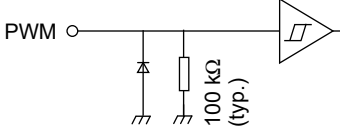
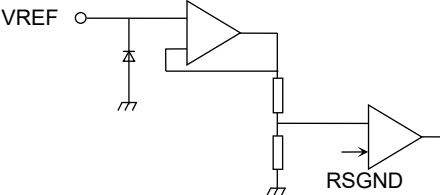
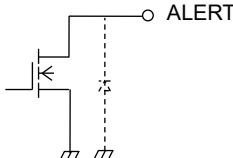
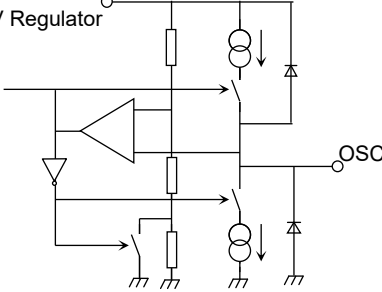
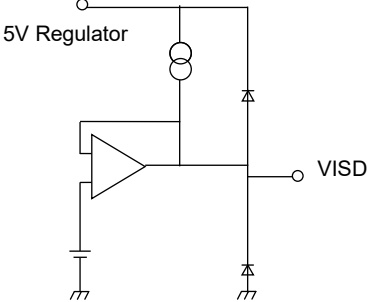


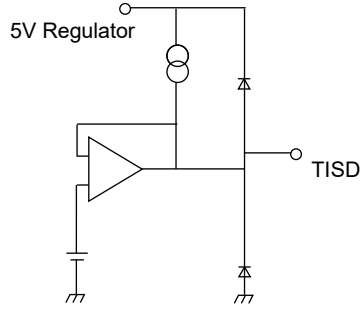
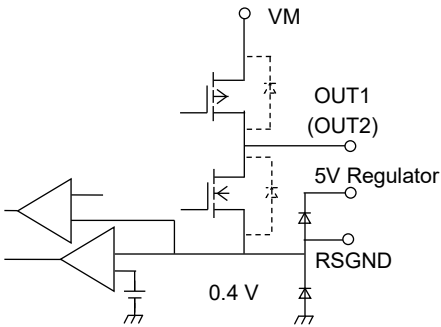
Figure 11.2 TB6569FG Thermal Performance Characteristics

12. I/O Equivalent Circuits

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

Table 12 I/O Equivalent Circuits

Pin name (Pin No.: TB6569FG)	I/O Signal	I/O Internal Circuit
IN1 (3) IN2 (5)	Digital input L: 0.8 V (max) H: 2 V (min)	
PWM (15)	Digital input L: 0.8 V (max) H: 2 V (min)	
VREF (16)	Analog input Input range: 0 V to 3.6 V	
ALERT (1)	Open-drain output An externally attached pull-up resistor enables the High output. H (High impedance): Abnormal operation (When the UVLO, TSD, VSD and/or ISD is activated) L: Normal operation	
OSC (2)	The pin connects a capacitor for controlling the oscillation frequency used in the PWM constant-current control. The oscillation frequency of the oscillator is approximated by the following formula: $f_{osc} = 0.42 / (C_{osc} [F] \times 10^3) = [Hz] (typ.)$	
VISD (13)	The pin connects a resistor controlling overcurrent detection threshold.	

Pin name (Pin No.: TB6569FG)	I/O Signal	I/O Internal Circuit
TISD (14)	The pin connects a resistor controlling overcurrent detection time.	
OUT1 (7) OUT2 (10) RSGND (8)	<p>The RSGND pin must be connected to a resistor for detection when it is used in the PWM constant-current control; it must be earthed to the ground, otherwise.</p> <p>Utmost care must be taken for designing the pin-arrangement pattern because a large current flows through these pins.</p>	

13. Functional Description

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

Timing charts may be simplified for explanatory purposes.

13.1. Input/Output Functions

Table 13.1 Input/Output Functions

Input			Output		
IN1	IN2	PWM	OUT1	OUT2	Mode
H	H	H	L	L	Short brake
		L	L	L	
L	H	H	L	H	CW/CCW
		L	L	L	Short brake
H	L	H	H	L	CCW/CW
		L	L	L	Short brake
L	L	H	OFF (Hi-Z)		Stop (a release of TSD and/or ISD)
		L			

13.2. Protective Operation Alert Output (ALERT)

The ALERT pin behaves as an open-drain output and provides a high-impedance state on output being pulled up by a resistor externally wired.

The output is Low when the TB6569FG/FTG performs a normal operation (in which state the operational mode is selectable through the IN1 pin and IN2 pin among CW, CCW, Short Brake and Stop modes.).

In any other cases (in which state the thermal shutdown circuit (TSD), overcurrent shutdown circuit (ISD), overvoltage shutdown circuit (VSD) and/or undervoltage lockout (UVLO) is activated), the output is High.

Driving both the IN1 pin and IN2 pin Low allows a release of the shutdown operations; the TB6569FG/FTG resumes the normal operations.

13.3. Undervoltage Lockout Circuit (UVLO)

The TB6569FG/FTG incorporates an undervoltage lockout circuit. When the supply voltage drops under 8 V (typ.), all the outputs are turned off (Hi-Z).

The UVLO circuit has a hysteresis of 0.7 V (typ.); the TB6569FG/FTG resumes the normal operation at 8.7 V (typ.).

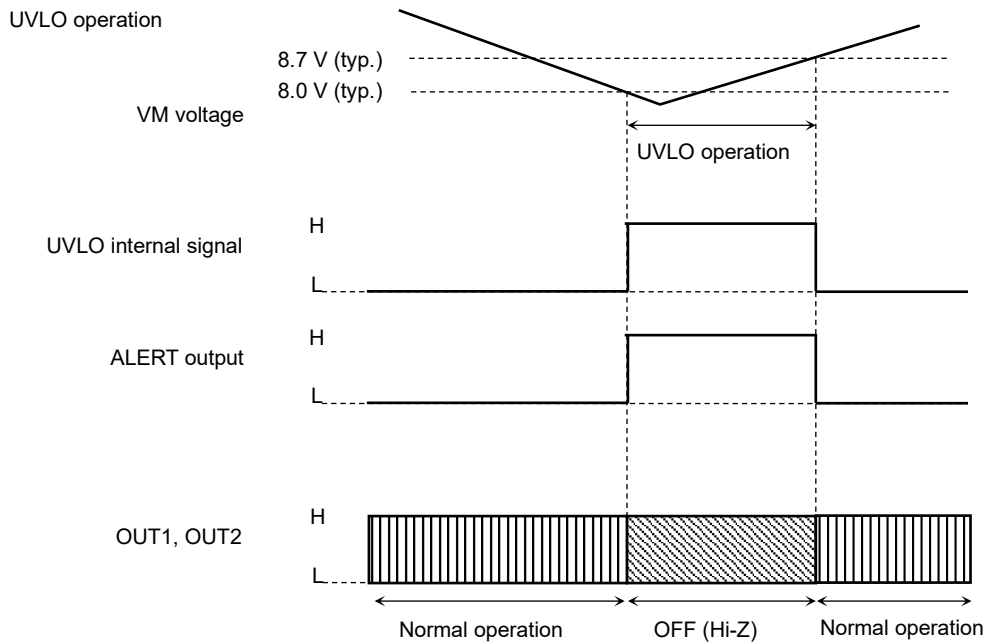


Figure 13.3 Timing Chart Example of UVLO Operation

13.4. Overvoltage Shutdown Circuit (VSD)

The TB6569FG/FTG incorporates an overvoltage shutdown circuit. If the supply voltage exceeds 53 V (typ.), all the outputs are turned off (Hi-Z). The VSD circuit has a hysteresis of 3 V (typ.); the TB6569FG/FTG resumes the normal operation at 50 V (typ.).

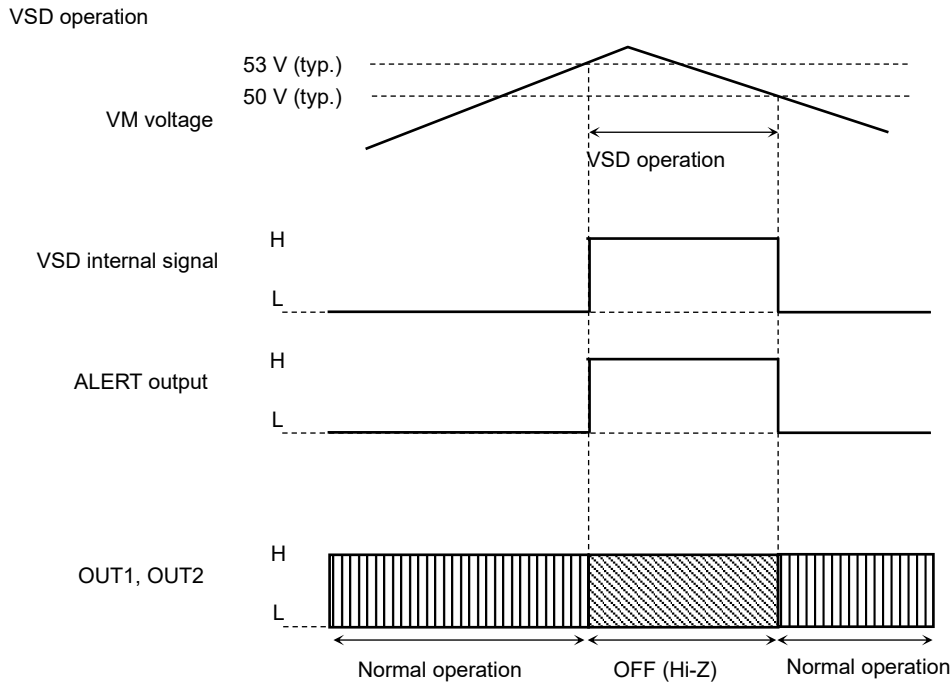


Figure 13.4 Timing Chart Example of VSD Operation

Note: The VSD circuit is activated if the absolute maximum voltage rating is violated. Note that the circuit is provided as an auxiliary only and does not necessarily provide the IC with a perfect protection from any kind of damages.

13.5. Thermal Shutdown Circuit (TSD) (Note)

The TB6569FG/FTG incorporates a thermal shutdown circuit. If the junction temperature (T_j) exceeds 170°C (typ.), all the outputs are turned off (Hi-Z).

Driving both the IN1 pin and IN2 pin Low allows a release of the shutdown operation; the TB6569FG/FTG resumes the normal operation.

TSD = 170°C (typ.)

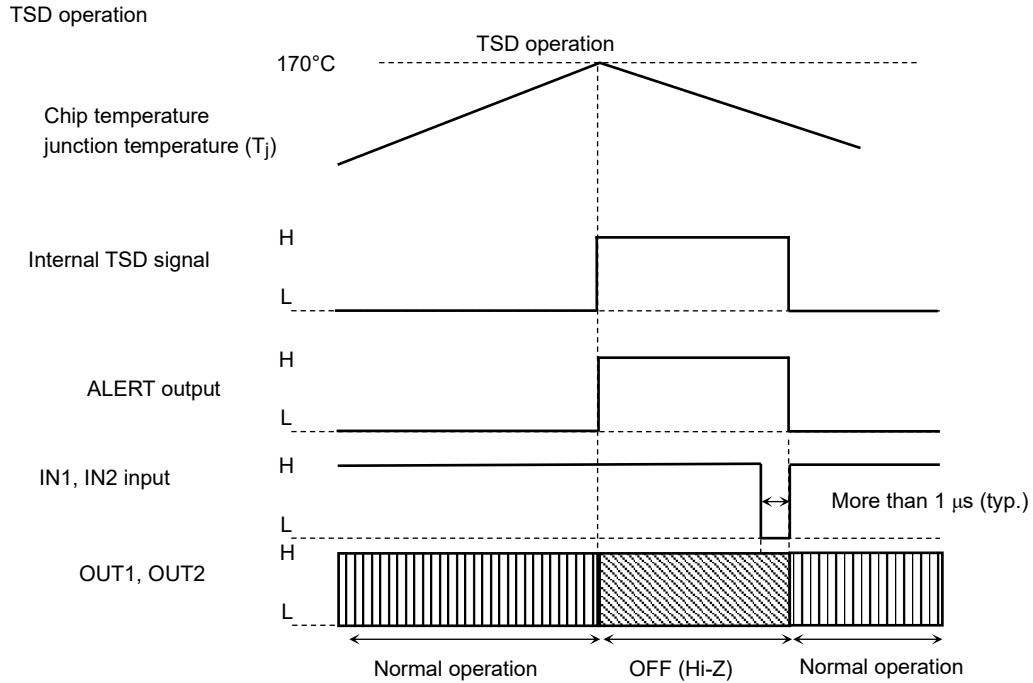


Figure 13.5 Timing Chart Example of TSD Operation

Note: The TSD circuit is activated if the absolute maximum junction temperature rating (T_j) of 150°C is violated. Note that the circuit is provided as an auxiliary only and does not necessarily provide the IC with a perfect protection from any kind of damages.

13.6. Overcurrent Shutdown Circuit (ISD)

Each of the four output power transistors has a built-in detection function to detect currents flowing in each transistor.

The detection current threshold can be set by the VISC pin resistor, and if any of the currents exceeds the detection current threshold for a duration greater than the detection time setting T, all outputs are turned off (high impedance: Hi-Z).

The detection time T can be set by external resistor on the TISD pin.

The IN1 pin: "L" and the IN2 pin: "L" will release the setting and allow the device to return to normal operation.

Detection current threshold of the external resistor, R1, of the VISC pin

10 kΩ: 6.3 A (typ.)

20 kΩ: 4.2A (typ.)

30 kΩ: 3.1 A (typ.)

Detection time threshold of the external resistor, R2, of the TISD pin

10 kΩ: 1.6 μs (typ.)

20 kΩ: 2.8 μs (typ.)

100 kΩ: 12.4 μs (typ.)

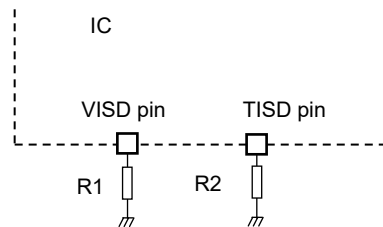


Figure 13.6.1 Example of ISD Circuit

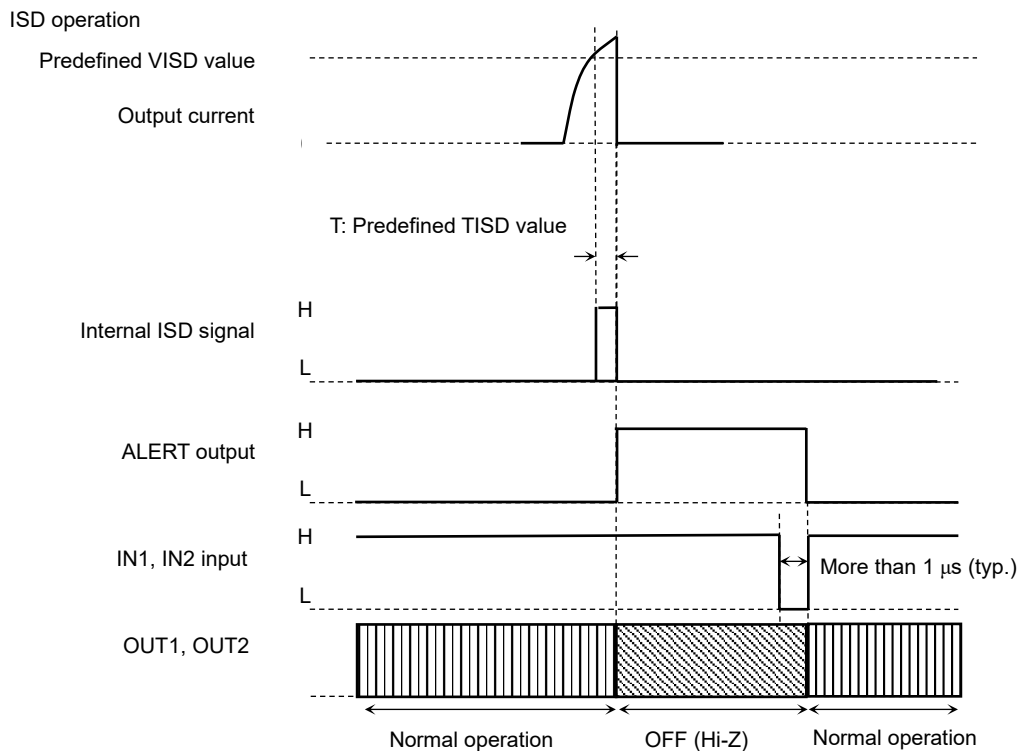


Figure 13.6.2 Timing Chart Example of ISD Operation

Note: The ISD circuit is activated if the absolute maximum current rating is violated. Note that the circuit is provided as an auxiliary only and does not necessarily provide the IC with a perfect protection from damages due to overcurrent caused by power fault, ground fault, load-short and the like.

13.7. Direct PWM Control

The motor rotation speed is controllable by the PWM input sent through the PWM pin. It is also possible to control the motor rotation speed by sending in the PWM signal through not the PWM pin but the IN1 and IN2 pins.

When the motor drive is controlled by the PWM input, the TB6569FG/FTG repeats operating in Normal Operation mode and Short Brake mode alternately.

For preventing the shoot-through current in the output circuit caused by the upper and lower power transistors being turned on simultaneously, the dead time is internally generated at the time the upper and lower power transistors switches between on and off.

This eliminates the need of inserting Off time externally; thus the PWM control with synchronous rectification is enabled.

Note that inserting Off time externally is not required on operation mode changes between CW and CCW, and CW (CCW) and Short Brake, again, because of the dead time generated internally.

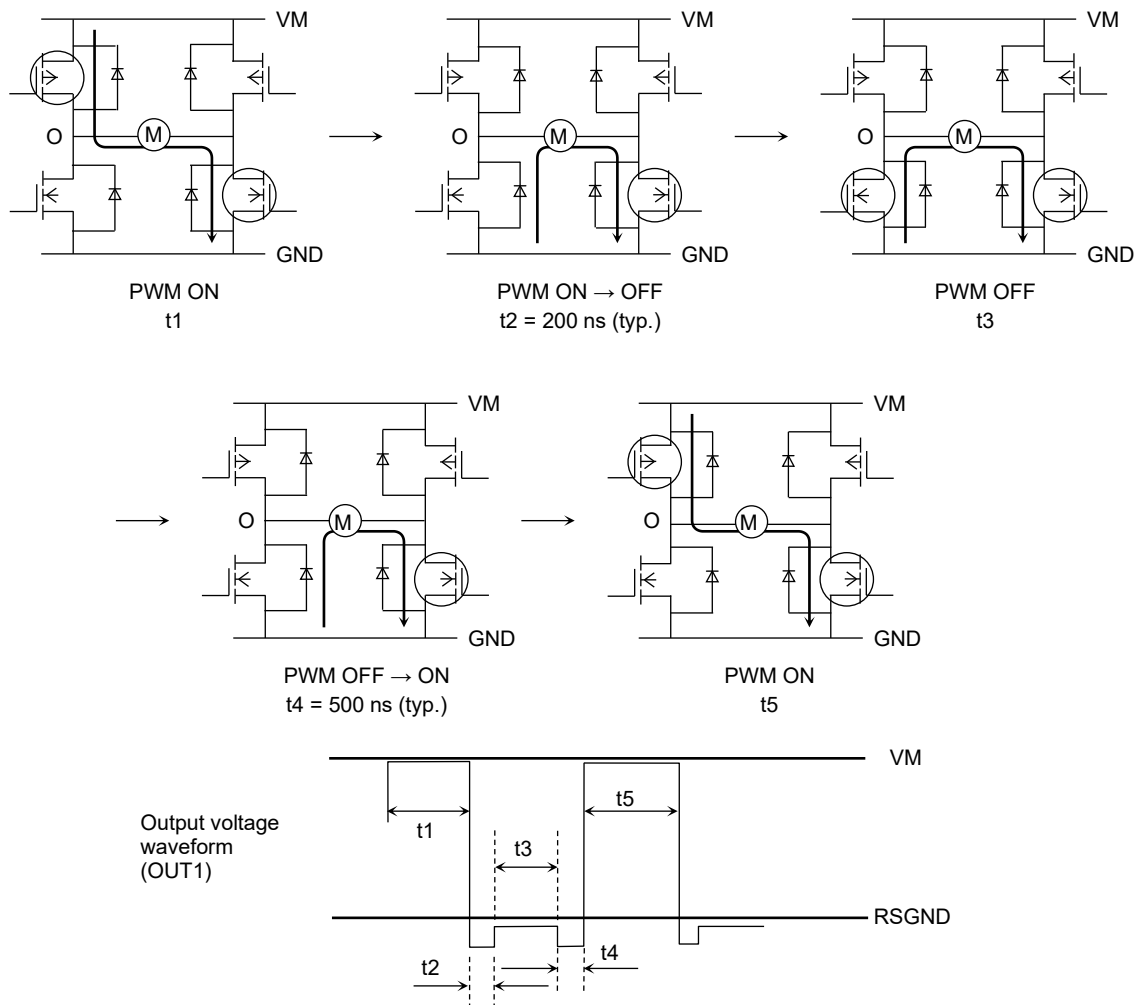


Figure 13.7 Direct PWM Control

13.8. Output Circuit

The switching characteristics of the output transistors of the OUT1 and OUT2 pins are as shown below:

Table 13.8 Output Circuit Switching Characteristics

Characteristic	Value	Unit
t_{pLH}	650 (typ.)	ns
t_{pHL}	450 (typ.)	
t_r	90 (typ.)	
t_f	130 (typ.)	

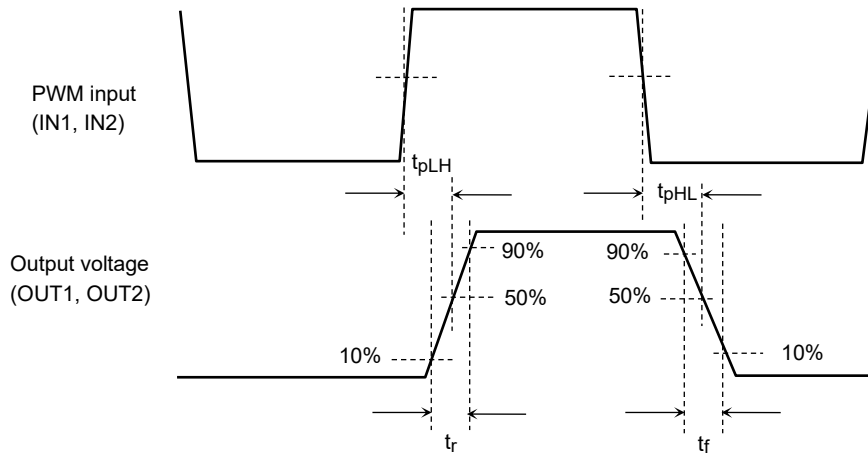


Figure 13.8 Output Circuit Switching Characteristics

13.9. PWM Constant-Current Control

The TB6569FG/FTG uses a peak current detection technique to keep the output current constant by applying constant voltage through the VREF pin. When running in Discharge mode, the TB6569FG/FTG powers the motor to operate in Short Brake mode.

(1) PWM constant-current control programming

The peak current upon the constant-current operation is determined by applying voltage on the VREF pin. The peak current value is calculated by the following equation:

$$I_o = VREF/R \times 1/10 \text{ [A]}$$

The PWM current-constant frequency is also programmable by using the capacitor of the OSC pin. The oscillation frequency is approximated by using the following equation:

$$f_{osc} = 0.42 / (C_{osc} \text{ [F]} \times 10^3) = \text{[Hz]} \text{ (typ.)}$$

For preventing the overvoltage on connecting a detection resistor, the RSGND pin is driven High (the outputs are turned off (Hi-Z)) when the applied voltage is over 0.4 V (typ.). The subsequent control of the RSGND is the same as the ISD circuit. The ALERT pin is also driven High. However, when the IN1 and IN2 pins are pulled Low, the ALERT pin is pulled Low and the TB6569FG/FTG resumes the normal operation.

It is recommended to use a detection resistor of over 0.1 Ω for the RSGND pin.

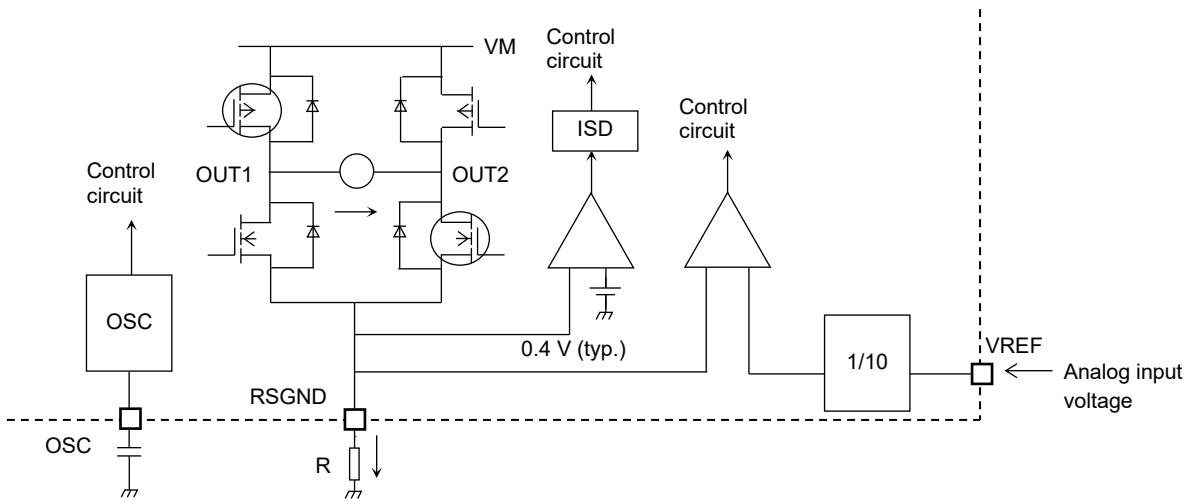


Figure 13.9.1 PWM Constant-current Control Circuit

(2) Constant-current chopping

The TB6569FG/FTG enters Discharge mode when V_{RSGND} reaches the predetermined voltage ($V_{REF}/10$).

After a lapse of four internal clocks generated by the OSC signal, the TB6569FG/FTG shifts to Charge mode.

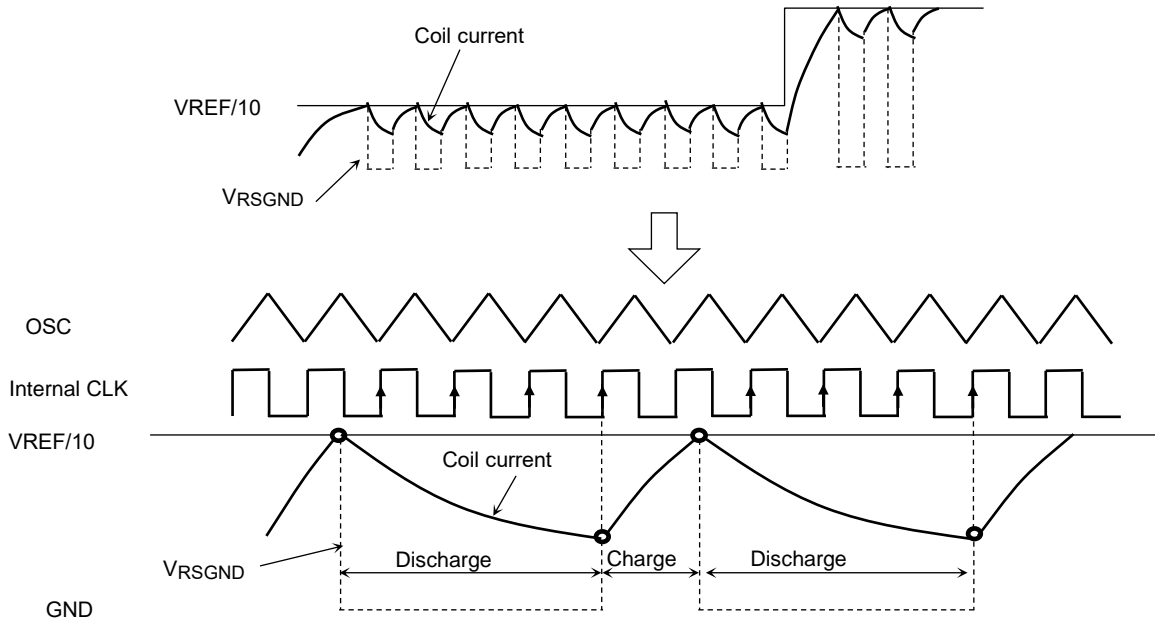


Figure 13.9.2 Constant-current Chopping

(3) Operation on change of predetermined current value (when in Discharge mode)

The TB6569FG/FTG enters Discharge mode as V_{RSGND} reaches the predetermined voltage ($V_{REF}/10$) and then transits to Charge mode after four internal clocks. However, if $V_{RSGND} > V_{REF}/10$ at the time, the TB6569FG/FTG goes back to Discharge mode. If $V_{RSGND} > V_{REF}/10$ after another four internal clocks, then the TB6569FG/FTG enters Charge mode and stays until V_{RSGND} reaches $V_{REF}/10$.

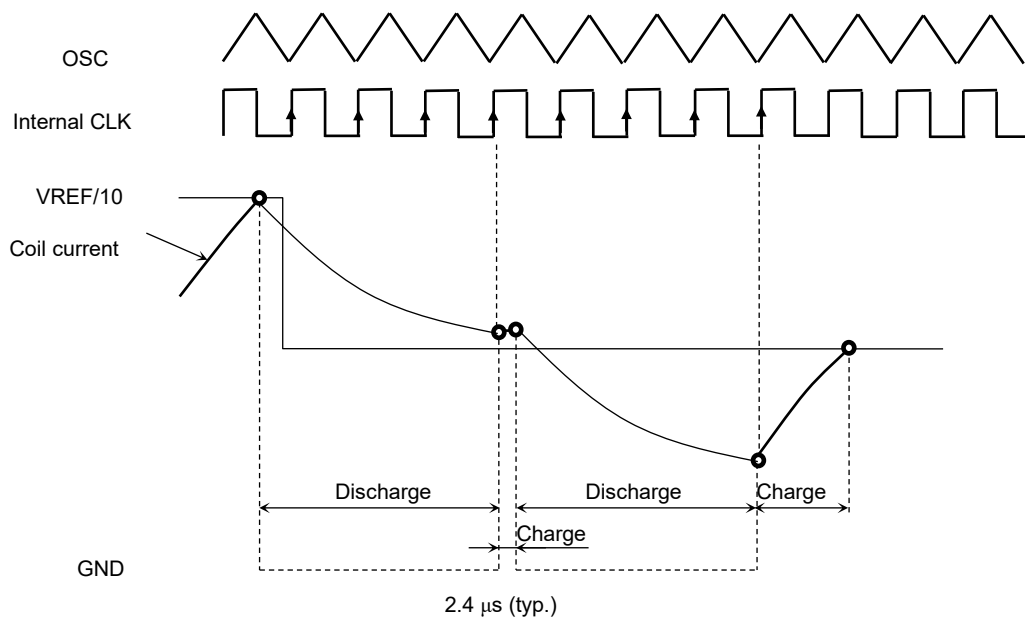


Figure 13.9.3 Operation on Change of Predetermined Current Value (Discharge mode)

(4) Operation on change of predetermined current value (when in Charge mode)

Even though VREF reaches the predetermined current value, Discharge mode continues for four internal clocks after that. And then Charge mode is entered.

Due to the peak current detection technique, the average current value of the constant-current operation shall be smaller than the predetermined value. Because this depends on characteristics of used motor coils, precise identification of the used motor coils must be performed when determining the current value.

When both the PWM constant-current control and the direct PWM control (applying the PWM input on the PWM pin, or on the IN1 and IN2 pins), Short Brake mode is preferentially selected.

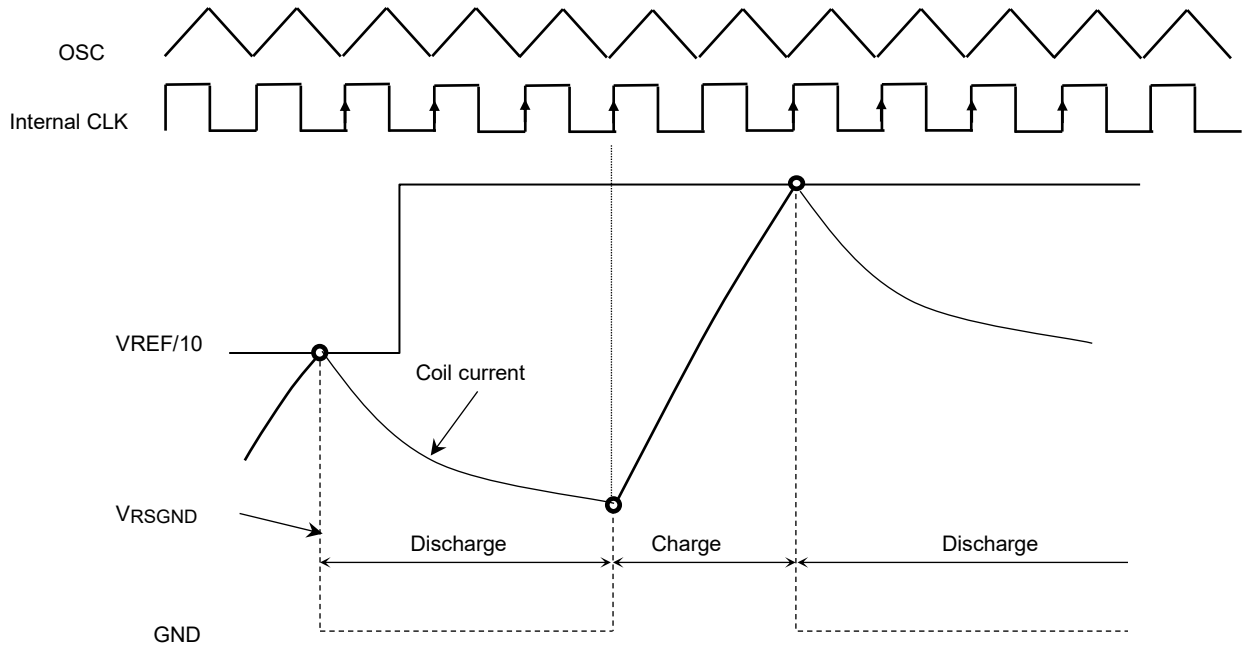


Figure 13.9.4 Operation on Change of Predetermined Current Value (Charge mode)

14. Package Dimensions

TB6569FG

HSOP16-P-300-1.00

Unit: mm

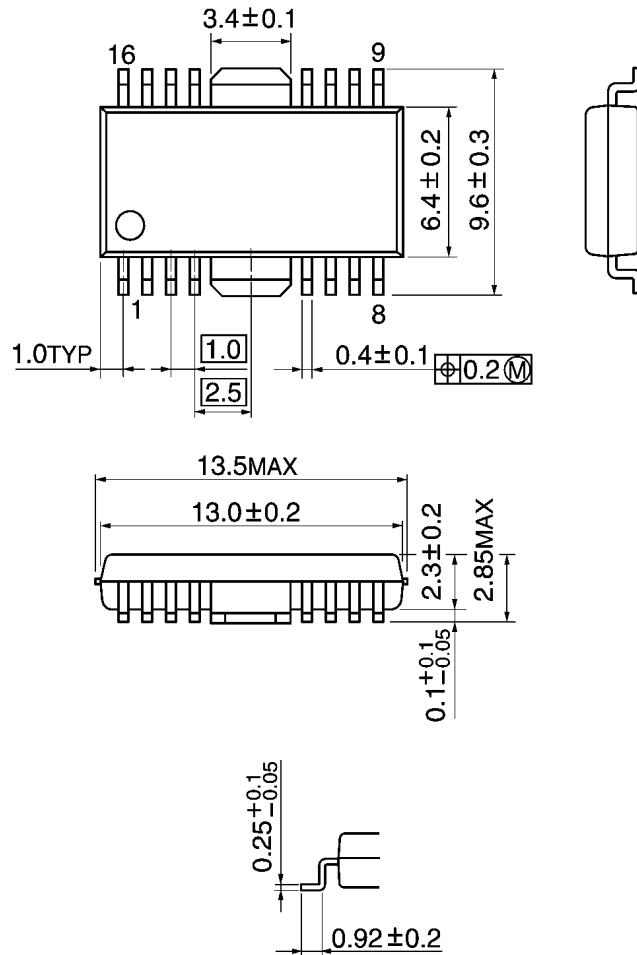


Figure 14.1 TB6569FG Package Dimensions

Weight: 0.5 g (typ.)

TB6569FTG

P-VQFN32-0505-0.50-002

Unit: mm

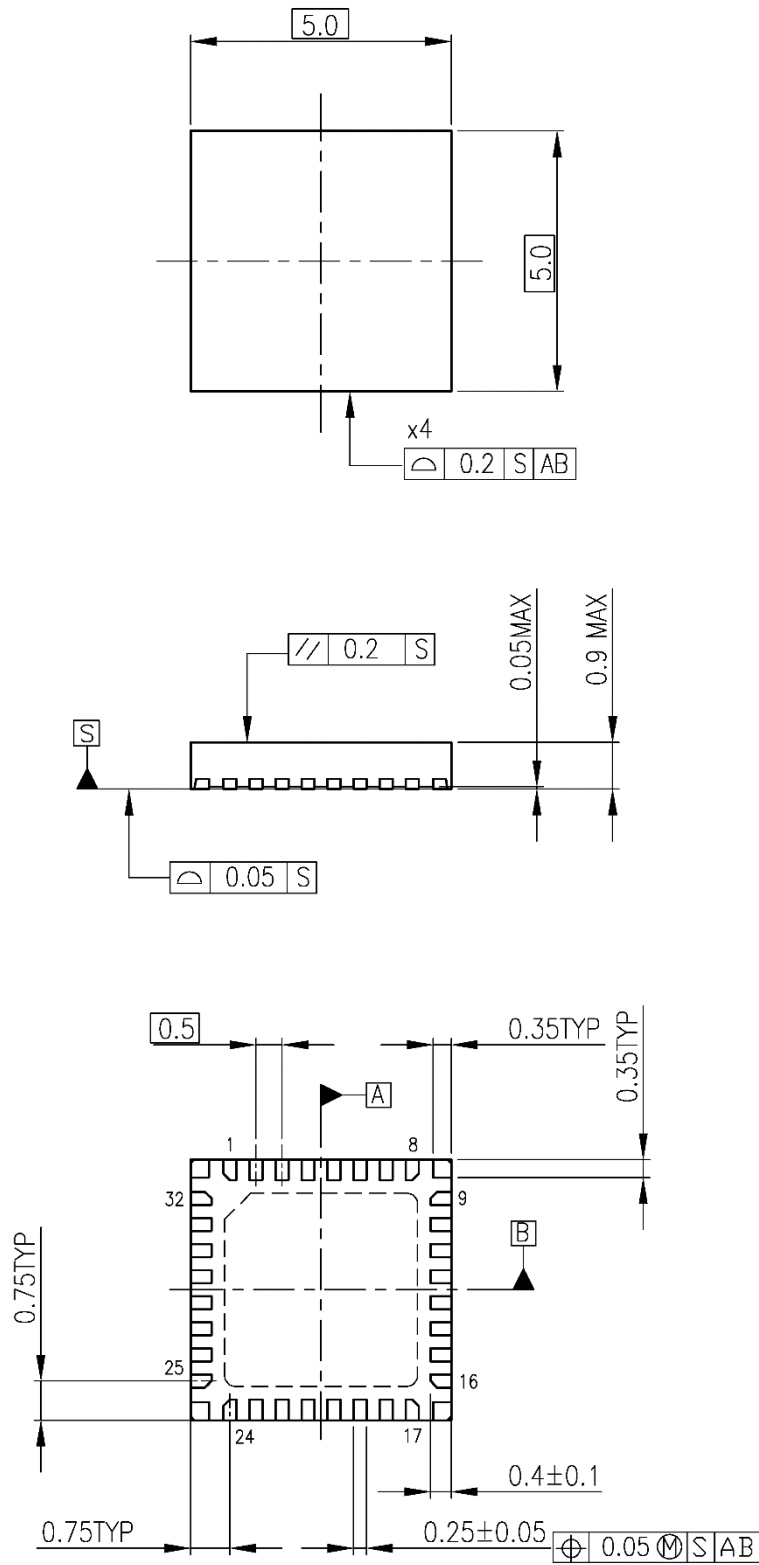


Figure 14.2 TB6569FTG Package Dimensions

Weight: 0.07 g (typ.)

15. Notes on Contents

Block Diagrams

Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purposes.

Equivalent Circuits

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

Timing Charts

Timing charts may be simplified for explanatory purposes.

Application Circuits

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Test Circuits

Components in the test circuits are used only to obtain and confirm the device characteristics. These components and circuits are not guaranteed to prevent malfunction or failure from occurring in the application equipment.

16. IC Usage Considerations

16.1. Notes on Handling of ICs

- (1) The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings. Exceeding the rating(s) may cause the device breakdown, damage, or deterioration, and may result injury by explosion or combustion.
- (2) Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of over current and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or load, causing a large current to continuously flow and the breakdown can lead smoke or ignition. To minimize the effects of the flow of a large current in case of breakdown, appropriate settings, such as fuse capacity, fusing time and insertion circuit location, are required.
- (3) If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or the negative current resulting from the back electromotive force at power OFF. IC breakdown may cause injury, smoke, or ignition. Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke, or ignition.
- (4) Do not insert devices in the wrong orientation or incorrectly. Make sure that the positive and negative terminals of power supplies are connected properly. Otherwise, the current or power consumption may exceed the absolute maximum rating, and exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion. In addition, do not use any device that is applied the current with inserting in the wrong orientation or incorrectly even just one time.

16.2. Points to Remember on Handling of ICs**(1) Over Current Protection Circuit**

Over current protection circuits (referred to as current limiter circuits) do not necessarily protect ICs under all circumstances. If the Over current protection circuits operate against the over current, clear the over current status immediately.

Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the over current protection circuit to not operate properly or IC breakdown before operation. In addition, depending on the method of use and usage conditions, if over current continues to flow for a long time after operation, the IC may generate heat resulting in breakdown.

(2) Thermal Shutdown Circuit

Thermal shutdown circuits do not necessarily protect ICs under all circumstances. If the thermal shutdown circuits operate against the over temperature, clear the heat generation status immediately. Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the thermal shutdown circuit to not operate properly or IC breakdown before operation.

(3) Heat Radiation Design

In using an IC with large current flow such as power amp, regulator, or driver, please design the device so that heat is appropriately radiated, not to exceed the specified junction temperature (T_j) at any time and condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, please design the device taking into consideration the effect of IC heat radiation with peripheral components.

(4) Back-EMF

When a motor rotates in the reverse direction, stops, or slows down abruptly, a current flow back to the motor's power supply due to the effect of back-EMF. If the current sink capability of the power supply is small, the device's motor power supply and output pins might be exposed to conditions beyond absolute maximum ratings. To avoid this problem, take the effect of back-EMF into consideration in system design.

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